

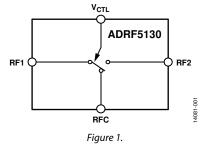
# High Power, 44 W Peak, Silicon SPDT, Reflective Switch, 0.7 GHz to 3.8 GHz

### **Data Sheet**

**FEATURES** 

# **ADRF5130**

#### FUNCTIONAL BLOCK DIAGRAM



Reflective, 50  $\Omega$  design Low insertion loss 0.6 dB typical to 2.0 GHz 0.7 dB typical to 3.5 GHz **High isolation** 50 dB typical to 2.0 GHz 46 dB typical to 3.5 GHz **High power handling** RF input power, continuous wave (CW) at T<sub>CASE</sub> = 85°C 43 dBm maximum operating 46.5 dBm absolute maximum rating **High linearity** 0.1 dB compression (P0.1dB): 46 dBm typical Input third-order intercept (IP3) 68 dBm typical to 2 GHz 65 dBm typical to 3.5 GHz ESD ratings Human body model (HBM): 2 kV, Class 2 Charged device model (CDM): 1.25 kV Single positive supply:  $V_{DD} = 5 V$ Positive control, TTL-compatible: VCTL = 0 V or VDD 24-lead, 4 mm × 4 mm LFCSP package (16 mm<sup>2</sup>)

#### **APPLICATIONS**

Cellular/4G infrastructure Wireless infrastructure Military and high reliability applications Test equipment Pin diode replacement

#### **GENERAL DESCRIPTION**

The ADRF5130 is a high power, reflective, 0.7 GHz to 3.8 GHz, silicon, single-pole, double-throw (SPDT) switch in a leadless, surface-mount package. The switch is ideal for high power and cellular infrastructure applications, like long-term evolution (LTE) base stations.

The ADRF5130 has high power handling of 43 dBm (maximum) and 0.1 dB compression (P0.1dB) of 46 dBm, with a low insertion loss of 0.6 dB at 2 GHz and 0.7 dB at 3.5 GHz. On-chip circuitry operates at a single, positive supply voltage of 5 V and typical supply current of 1.06 mA, making the ADRF5130 an ideal alternative to pin diode-based switches.

The device comes in a RoHS compliant, compact, 24-lead, 4 mm  $\times$  4 mm LFCSP package.

Rev. C

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## TABLE OF CONTENTS

Features	1
Applications	1
Functional Block Diagram	1
General Description	1
Revision History	2
Specifications	3
Absolute Maximum Ratings	4
ESD Caution	4
Pin Configuration and Function Descriptions	5

#### **REVISION HISTORY**

6/2020—Rev. B to Rev. C
Changed Operating Frequency from 0.7 GHz to 3.5 GHz to
0.7 GHz to 3.8 GHz Throughout
Changes to Data Sheet Title, Features Section, and General
Description Section
Changes to Table 1 3

Interface Schematics	5
Typical Performance Characteristics	6
Insertion Loss, Isolation, Return Loss, and IP3	6
Theory of Operation	7
Applications Information	8
Evaluation Board	8
Outline Dimensions	10
Ordering Guide	10

5/2018—Rev. A to Rev. B
Change to RFC to RF2 Column, Table 57
Updated Outline Dimensions 10
•
1/2017—Rev. 0 to Rev. A
Changes to Ordering Guide10

7/2016—Revision 0: Initial Version

### **SPECIFICATIONS**

 $V_{\text{DD}}$  = 5 V,  $V_{\text{CTL}}$  = 0 V or  $V_{\text{DD}},$   $T_{\text{A}}$  = 25°C, 50  $\Omega$  system, unless otherwise noted.

#### Table 1.

Parameter	Symbol	Test Conditions/Comments	Min	Тур	Мах	Unit
FREQUENCY RANGE			0.7		3.8	GHz
INSERTION LOSS		0.7 GHz to 2.0 GHz		0.6		dB
		2.0 GHz to 3.5 GHz		0.7		dB
		3.5 GHz to 3.8 GHz		0.75		dB
ISOLATION						
RFC to RF1 or RF2 (Worst Case)		0.7 GHz to 2.0 GHz		50		dB
		2.0 GHz to 3.8 GHz		46		dB
RF1 to RF2 (Worst Case)		0.7 GHz to 2.0 GHz		51		dB
		2.0 GHz to 3.8 GHz		40		dB
RETURN LOSS						
RFC		0.7 GHz to 2.0 GHz		23		dB
		2.0 GHz to 3.5GHz		17		dB
		3.5 GHz to 3.8 GHz		15		dB
RFC to RF1 or RF2		0.7 GHz to 2.0 GHz		21		dB
		2.0 GHz to 3.5 GHz		17		dB
		3.5 GHz to 3.8 GHz		16		dB
SWITCHING SPEED						
Time						
Rise and Fall	trise, t <sub>FALL</sub>	90% to 10% of RF output		155		ns
On and Off	ton, toff	50% V <sub>CTL</sub> to 10% to 90% of RF output		750		ns
RADIO FREQUENCY (RF) SETTLING TIME		50% V <sub>CTL</sub> to 0.1 dB margin of final RF output	1.8		μs	
INPUT POWER						P
0.1 dB Compression	P0.1dB		46		dBm	
INPUT THIRD-ORDER INTERCEPT	IP3	Two-tone input power = 25 dBm/tone		-		
		0.7 GHz to 2 GHz		68		dBm
		2 GHz to 3.8 GHz		65		dBm
RECOMMENDED OPERATING						
CONDITIONS						
Voltage Range						
Bias	V <sub>DD</sub>		4.5		5.4	V
Control	V <sub>CTL</sub>		0		$V_{DD}$	V
Maximum RF Input Power						
$T_{CASE} = 105^{\circ}C$		Continuous wave			41	dBm
$T_{CASE} = 85^{\circ}C$		Continuous wave			43	dBm
		8 dB peak to average ratio (PAR) LTE, average			38	dBm
		8 dB PAR LTE, single event (<10 sec), average			44	dBm
$T_{CASE} = 25^{\circ}C$		Continuous wave			44.5	dBm
Case Temperature Range	TCASE		-40		+105	°C
DIGITAL INPUT CONTROL VOLTAGE		$V_{DD} = 4.5$ V to 5.4 V, $T_{CASE} = -40^{\circ}$ C to $+105^{\circ}$ C at $<1 \mu$ A				
Low Range	VIL	typical	0		0.8	v
High Range	VIL VIH		1.3		0.8 5.0	v
SUPPLY CURRENT	-	$V_{DD} = 5 V$	1.5	1.04	5.0	
SUPPLI CUKKENI	I <sub>DD</sub>	$v_{DD} = 5 v$		1.06		mA

### **ABSOLUTE MAXIMUM RATINGS**

#### Table 2.

Parameter	Rating
Bias Voltage Range (V <sub>DD</sub> )	–0.3 V to +5.5 V
Control Voltage Range (V <sub>CTL</sub> )	–0.3 V to +5.5 V
RF Input Power, <sup>1</sup> Continuous Wave	46.5 dBm
Channel Temperature	135°C
Storage Temperature Range	–65°C to +150°C
Operating Temperature Range	–40°C to +105°C
Peak Reflow Temperature (MSL3) <sup>2</sup>	260°C
Thermal Resistance (Channel to Package Bottom)	17°C/W
Electrostatic Discharge (ESD) Sensitivity	
HBM	2 kV (Class 2)
CDM	1.25 kV

Stresses at or above those listed under Absolute Maximum Ratings may cause permanent damage to the product. This is a stress rating only; functional operation of the product at these or any other conditions above those indicated in the operational section of this specification is not implied. Operation beyond the maximum operating conditions for extended periods may affect product reliability.

#### **ESD CAUTION**



**ESD** (electrostatic discharge) sensitive device. Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

<sup>1</sup> For the recommended operating conditions, see Table 1.

<sup>2</sup> See the Ordering Guide section.

### **PIN CONFIGURATION AND FUNCTION DESCRIPTIONS**

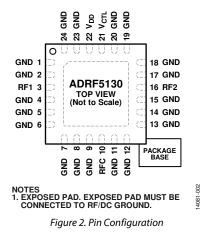


Table 3. Pin Function Descriptions

Pin No.	Mnemonic	Description
1, 2, 4 to 9, 11 to 15, 17 to 20, 23, 24	GND	Ground. The package bottom has an exposed metal pad that must connect to the printed circuit board (PCB) RF/dc ground. See Figure 3 for the GND interface schematic.
3	RF1	RF Output Port 1. This pin is dc-coupled and matched to 50 $\Omega$ . A dc blocking capacitor is required on this pin.
10	RFC	RF Input Common Port. This pin is dc-coupled and matched to 50 $\Omega$ . A dc blocking capacitor is required on this pin.
16	RF2	RF Output Port 2. This pin is dc-coupled and matched to 50 $\Omega$ . A dc blocking capacitor is required on this pin.
21	V <sub>CTL</sub>	Control Input. See Figure 4 for the $V_{CTL}$ interface schematic. Refer to Table 4 and the recommended digital input control voltage range in Table 1.
22	V <sub>DD</sub>	Supply Voltage. See Figure 4 for the $V_{DD}$ interface schematic.
	EPAD	Exposed Pad. Exposed pad must be connected to RF/dc ground.

#### Table 4. Truth Table

	Signal Path State		
Control Input (V <sub>CTL</sub> ) State	RFC to RF1	RFC to RF2	
Low	Off	On	
High	On	Off	

#### **INTERFACE SCHEMATICS**

GND 003 Ŷ 14081 Figure 3. GND Interface Schematic

 $V_{DD}$ V<sub>CTL</sub> O-081-004

Figure 4. Control Interface Schematic

## **TYPICAL PERFORMANCE CHARACTERISTICS**

INSERTION LOSS, ISOLATION, RETURN LOSS, AND IP3

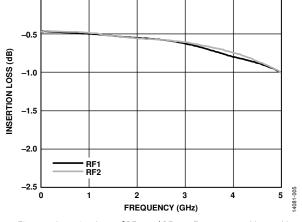
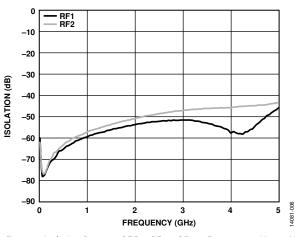
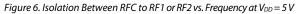


Figure 5. Insertion Loss of RF1 and RF2 vs. Frequency at  $V_{DD} = 5 V$ 





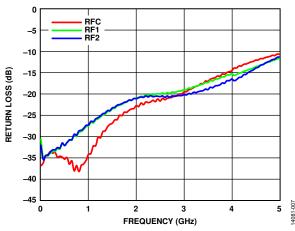


Figure 7. Return Loss vs. Frequency at  $V_{DD} = 5 V$  (RFC, RF1, and RF2)

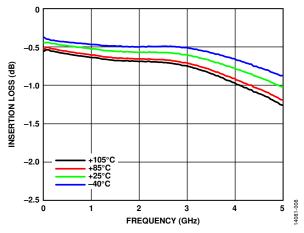


Figure 8. Insertion Loss vs. Frequency over Temperature at  $V_{DD} = 5 V$ 

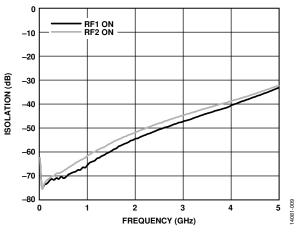


Figure 9. Isolation Between RF1 and RF2 vs. Frequency at  $V_{DD} = 5 V$ , Switch Mode On

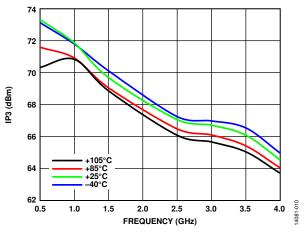


Figure 10. IP3 vs. Frequency over Temperature,  $V_{DD} = 5 V$ 

### **THEORY OF OPERATION**

The ADRF5130 requires a single-supply voltage applied to the  $V_{\rm DD}$  pin. Bypass capacitors are recommended on the supply line to minimize RF coupling.

A digital control voltage applied to the  $V_{CTL}$  pin controls the ADRF5130. A small bypassing capacitor is recommended on these digital signal lines to improve the RF signal isolation.

The ADRF5130 is internally matched to 50  $\Omega$  at the RF input port (RFC) and the RF output ports (RF1 and RF2); therefore, no external matching components are required. The RFx pins are dc-coupled, and dc blocking capacitors are required on the RF lines. The design is bidirectional; the input and outputs are interchangeable. The ideal power-up sequence of the ADRF5130 is as follows:

- 1. Connect to GND.
- 2. Power up  $V_{DD}$ .

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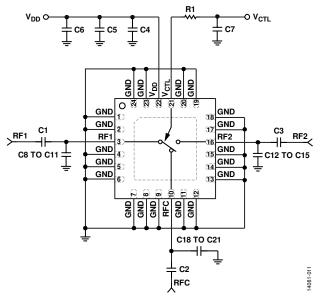
- 3. Power up the digital control input. Powering the digital control input before the V<sub>DD</sub> supply can inadvertently forward-bias and damage the ESD protection structures.
- 4. Power up the RF input. Depending on the logic level applied to the V<sub>CTL</sub> pin, one RF output port (for example, RF1) is set to on mode, by which an insertion loss path is provided from the input to the output, while the other RF output port (for example, RF2) is set to off mode, by which the output is isolated from the input.

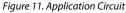
#### Table 5. Switch Operation Mode

	Switch Mode				
Digital Control Input (V <sub>CTL</sub> )	RFC to RF1	RFC to RF2			
0	Off mode: the RF1 port is isolated from the RFC port and is internally terminated to a 50 $\Omega$ load to absorb the applied RF signals.	On mode: a low insertion loss path from the RFC port to the RF2 port.			
1	On mode: a low insertion loss path from the RFC port to the RF1 port.	Off mode: the RF2 port is isolated from the RFC port and becomes open reflective.			

### **APPLICATIONS INFORMATION**

Generate the evaluation PCB used in the application circuit shown in Figure 11 with proper RF circuit design techniques. Signal lines at the RF port must have a 50  $\Omega$  impedance, and the package ground leads and backside ground slug must connect directly to the ground plane, as shown in Figure 14.





#### **EVALUATION BOARD**

The ADRF5130 evaluation board has eight metal layers and dielectrics between each layer (see Figure 12). The top and the bottom metal layers have copper thickness of 2 oz (2.7 mil), whereas the metal layers in between them have 1 oz copper (1.3 mil) thickness. The top dielectric material is 10 mil Rogers RO4350, which exhibits a very low thermal coefficient, offering control over thermal rise of the board. The dielectrics between other metal layers are FR-4. The overall board thickness achieved is 62 mil.

Figure 13 shows the top view of the ADRF5130 evaluation board.

The top copper layer has all RF and dc traces, whereas the other seven layers provide good ground and help to handle the thermal rise on the evaluation board caused by the high power of the ADRF5130. In addition, for proper thermal grounding, many via holes are provided around the transmission lines and under the exposed pad of the package. RF transmission lines on the ADRF5130 evaluation board are coplanar wave guide design with an 18 mil width and a ground spacing of 13 mil. For controlling the thermal rise of the ADRF5130 evaluation board at high temperatures and power levels, it is recommended to use a heat sink and a mini dc fan.

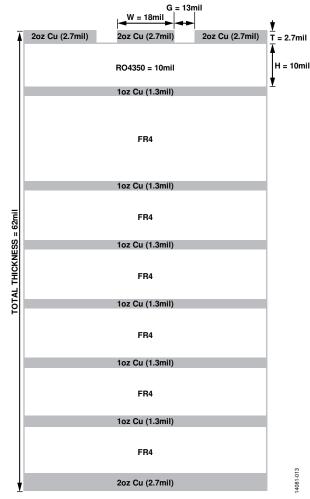


Figure 12. Evaluation Board Cross-Sectional View

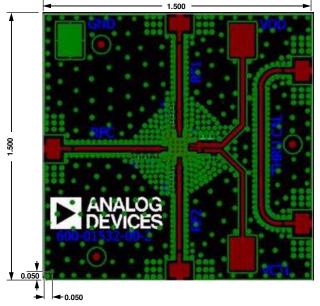


Figure 13. Evaluation Board Top View

4081-014

### **Data Sheet**

# ADRF5130

Figure 14 shows the ADRF5130 evaluation board with all components populated. The VDD supply port connects to TP1. The VDD supply trace has three bypass capacitors 100 pF, 1  $\mu$ F, and 1 nF. The TP2 test point connects to the control voltage port (VCTL). The control trace has a 100 pF bypass capacitor and 0  $\Omega$  resistor. The ground reference connects to GND. A 100 pF dc blocking capacitor is used on all RF traces that connect the RF1, RF2, and RFC ports to the J1, J2, and J3 connectors,

respectively. The connectors used are 2.9 mm end launch SMA connectors. Unpopulated capacitor positions are available on all RF traces to provide extra matching. A through transmission line (THRU CAL) is available on the ADRF5130 evaluation board that can measure board loss on the printed circuit board (PCB).

Table 6 shows the bill of materials for the ADRF5130 evaluation board. The evaluation board shown in Figure 14 is available from Analog Devices, Inc., upon request.

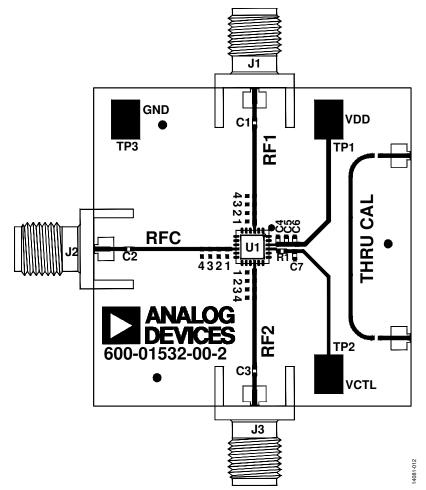


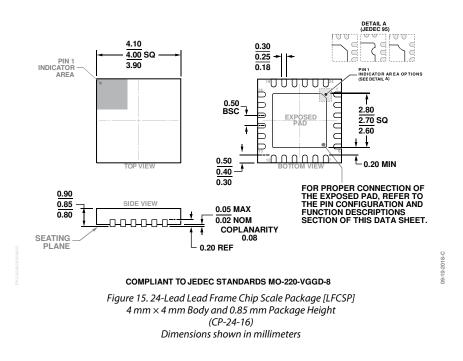
Figure 14. ADRF5130-EVALZ Evaluation Board

#### Table 6. Bill of Materials for the ADRF5130-EVALZ Evaluation Board

<b>Reference Designator</b>	Description
J1 to J3	PCB mount SMA connectors
C1 to C4, C7	100 pF capacitors, 0402 package
C5	1 nF capacitor, 0402 package
C6	1 μF capacitor, 0402 package
C8 to C15, C18 to C21	Do not insert (DNI)
R1	0 Ω resistor, 0402 package
TP1, TP2, TP3	Surface-mount test points
U1	ADRF5130 SPDT switch
РСВ	600-01532-00-2 <sup>1</sup> evaluation PCB; circuit board material: Rogers RO4350 or Arlon 25FR

<sup>1</sup> Reference this evaluation board number when ordering the complete evaluation board.

### **OUTLINE DIMENSIONS**



#### **ORDERING GUIDE**

Model <sup>1</sup>	Temperature Range	MSL Rating <sup>2</sup>	Package Description	Package Option
ADRF5130BCPZ	-40°C to +105°C	MSL3	24-Lead Lead Frame Chip Scale Package [LFCSP]	CP-24-16
ADRF5130BCPZ-R7	-40°C to +105°C	MSL3	24-Lead Lead Frame Chip Scale Package [LFCSP]	CP-24-16
ADRF5130-EVALZ	-40°C to +105°C		Evaluation Board	

 $^{1}$  Z = RoHS Compliant Part.

<sup>2</sup> See the Absolute Maximum Ratings section.



Rev. C | Page 10 of 10